BLF0910H6L500; BLF0910H6LS500

Power LDMOS transistor

AMPLEON

Rev. 2 — 13 April 2017

Product data sheet

1. Product profile

1.1 General description

A 500 W LDMOS power transistor for industrial applications at frequency of 915 MHz.

The BLF0910H6L500 and BLF0910H6LS500 are designed for high-power CW applications and are assembled in high performance ceramic packages.

Table 1. Typical performance

RF performance at V_{DS} = 50 V; I_{Dq} = 90 mA in a class-AB application circuit.

| Test signal | f | V _{DS} | P_L | Gp | ησ |
|------------------|-------|-----------------|-------|------|------|
| | (MHz) | (V) | (W) | (dB) | (%) |
| CW [1] | 915 | 50 | 500 | 18 | 61 |
| CW pulsed [2][3] | 915 | 50 | 500 | 19.5 | 62.5 |

- [1] $T_{case} = 65 \, ^{\circ}C$.
- [2] $T_{case} = 25 \, ^{\circ}C$.
- [3] $t_p = 100 \,\mu\text{s}; \, \delta = 10 \,\%.$

1.2 Features and benefits

- High efficiency
- Easy power control
- Excellent ruggedness
- Integrated ESD protection
- Designed for broadband operation (900 MHz to 930 MHz)
- Internally input matched
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

Industrial applications in the 915 MHz ISM band

2. Pinning information

Table 2. Pinning

| Pin | Description | | Simplified outline | Graphic symbol |
|---------|-------------------|-----|--------------------|----------------------|
| BLF0910 | H6L500 (SOT502A) | | | |
| 1 | drain | | | |
| 2 | gate | | 5 3 | 1 |
| 3 | source | [1] | 2 | 2 — 3 3 sym112 |
| BLF0910 | H6LS500 (SOT502B) | | | |
| 1 | drain | | | _ |
| 2 | gate | | 1 3 | 1 |
| 3 | source | [1] | 2 | 2 — 3 sym112 |

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Packag | ge | | |
|----------------|--------|--|---------|--|
| | Name | Description | | |
| BLF0910H6L500 | - | flanged ceramic package; 2 mounting holes; 2 leads | SOT502A | |
| BLF0910H6LS500 | - | earless flanged ceramic package; 2 leads | SOT502B | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Min | Max | Unit |
|------------------|--------------------------|-----|-------|------|
| V_{DS} | drain-source voltage | - | 114.5 | V |
| V_{GS} | gate-source voltage | -6 | +11 | V |
| T _{stg} | storage temperature | -65 | +150 | °C |
| Tj | junction temperature [1] | - | 225 | °C |

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|-------------------------|--|---|-----|------|
| R _{th(j-case)} | thermal resistance from junction to case | T _{case} = 80 °C; P _L = 500 W | 0.2 | K/W |

BLF0910H6L500_H6LS500

Characteristics

Table 6. **DC** characteristics

 $T_i = 25$ °C, unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|----------------------------------|--|-------|-------|------|------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 4 \text{ mA}$ | 114.5 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | V _{DS} = 10 V; I _D = 400 mA | 1.25 | 1.9 | 2.35 | V |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 50 V | - | - | 2.8 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$ | - | 60 | - | Α |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 280 | nA |
| g _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 20 A | - | 29 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 14 \text{ A}$ | - | 0.078 | - | Ω |

Table 7. **RF** characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 10 %; f = 915 MHz; RF performance at V_{DS} = 50 V; I_{Da} = 90 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------|-------------------|------------------------|-----|------|-----|------|
| Gp | power gain | P _L = 500 W | 15 | 19 | - | dB |
| RLin | input return loss | P _L = 500 W | - | -18 | -7 | dB |
| η_{D} | drain efficiency | P _L = 500 W | 59 | 63.5 | - | % |

Test information 7.

7.1 Ruggedness in class-AB operation

The BLF0910H6L500 and BLF0910H6LS500 are capable of withstanding a load mismatch corresponding to VSWR = 30:1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 90 mA; P_L = 500 W (CW); f = 915 MHz.

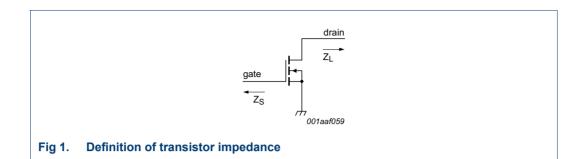
7.2 Impedance information

Typical impedance

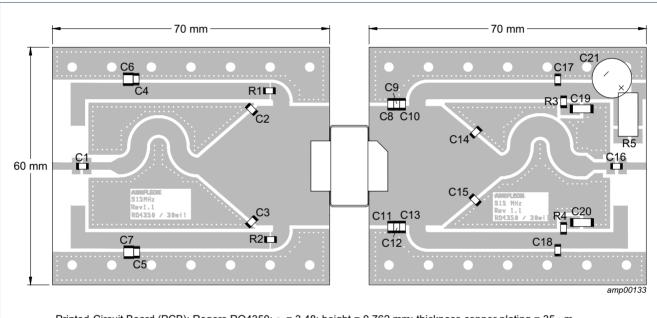
Measured load-pull Z_S and Z_L device impedances; $I_{Dq} = 90$ mA; $V_{DS} = 50$ V; typical values unless otherwise specified.

| f | Z _S [1] | Z _L [1] |
|-------|--------------------|---------------------|
| (MHz) | (Ω) | (Ω) |
| 915 | 1.8 – 1.4j | 0.6 + 0.35j |

[1] Z_S and Z_L defined in Figure 1.



7.3 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350; ϵ_r = 3.48; height = 0.762 mm; thickness copper plating = 35 μ m. See Table 9 for a list of components.

Fig 2. Component layout for application circuit

Table 9.List of componentsSee Figure 2 for component layout.

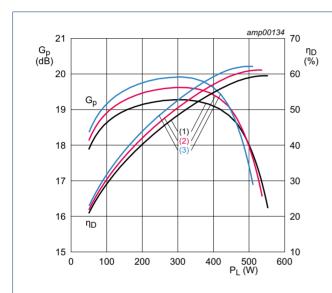
| Component | Description | Value | Remarks |
|-------------------|-----------------------------------|---------------|----------------------------|
| C1, C16 | multilayer ceramic chip capacitor | 470 pF | ATC 800B |
| C2, C3 | multilayer ceramic chip capacitor | 2.4 pF | ATC 800B |
| C4, C5, C17, C18 | multilayer ceramic chip capacitor | 100 pF | ATC 800B |
| C6, C7 | multilayer ceramic chip capacitor | 4.7 μF, 50 V | Murata: GRM32ER71H475KA88L |
| C8, C11 | multilayer ceramic chip capacitor | 5.6 pF | ATC 800B |
| C9, C10, C12, C13 | multilayer ceramic chip capacitor | 4.7 pF | ATC 800B |
| C14, C15 | multilayer ceramic chip capacitor | 0.9 pF | ATC 800B |
| C19, C20 | multilayer ceramic chip capacitor | 4.7 μF, 100 V | TDK: C5750X7R2A475KT/A |
| C21 | electrolytic capacitor | 470 μF, 63 V | |

Table 9. List of components ...continued

See Figure 2 for component layout.

| Component | Description | Value | Remarks |
|-----------|----------------|--------|------------------------|
| R1, R2 | resistor | 10 Ω | SMD1206 |
| R3, R4 | resistor | 3 Ω | SMD1206 |
| R5 | shunt resistor | 0.01 Ω | Ohmite: FC4L110R010FER |

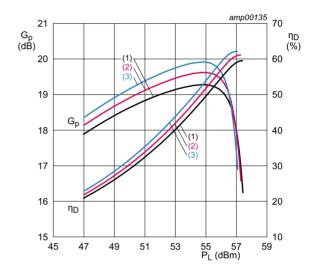
7.4 Graphical data



 $V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

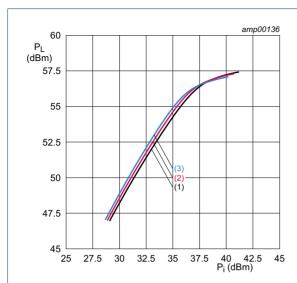
Fig 3. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 90 mA.

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

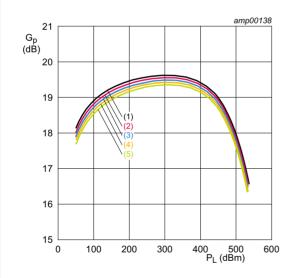
Fig 4. Power gain and drain efficiency as function of output power; typical values



$$V_{DS} = 50 \text{ V}; I_{Dq} = 90 \text{ mA}.$$

- (1) f = 902 MHz
- (2) f = 915 MHz
- (3) f = 928 MHz

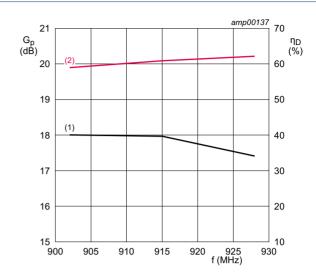
Fig 5. Output power as a function of input power; typical values



V_{DS} = 50 V; f = 915 MHz.

- (1) $I_{Dq} = 90 \text{ mA}$
- (2) $I_{Dq} = 80 \text{ mA}$
- (3) $I_{Dq} = 70 \text{ mA}$
- (4) $I_{Dq} = 60 \text{ mA}$
- (5) $I_{Dq} = 50 \text{ mA}$

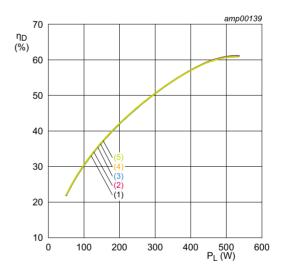
Fig 7. Power gain as a function of output power; typical values



 V_{DS} = 50 V; I_{Dq} = 90 mA; P_L = 500 W.

- (1) G_p
- (2) η_D

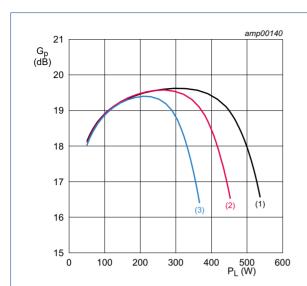
Fig 6. Power gain and drain efficiency as a function of frequency; typical values



 $V_{DS} = 50 \text{ V}; f = 915 \text{ MHz}.$

- (1) $I_{Dq} = 90 \text{ mA}$
- (2) $I_{Dq} = 80 \text{ mA}$
- (3) $I_{Dq} = 70 \text{ mA}$
- (4) $I_{Dq} = 60 \text{ mA}$
- (5) $I_{Dq} = 50 \text{ mA}$

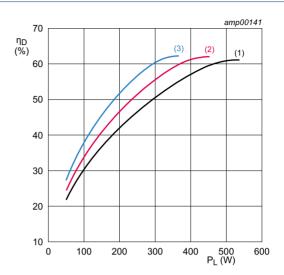
Fig 8. Drain efficiency as a function of output power; typical values



 $I_{Dq} = 90 \text{ mA}$; f = 915 MHz.

- (1) $V_{DS} = 50 \text{ V}$
- (2) $V_{DS} = 45 \text{ V}$
- (3) $V_{DS} = 40 \text{ V}$

Fig 9. Power gain as a function of output power; typical values

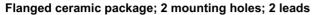


 $I_{Dq} = 90 \text{ mA}$; f = 915 MHz.

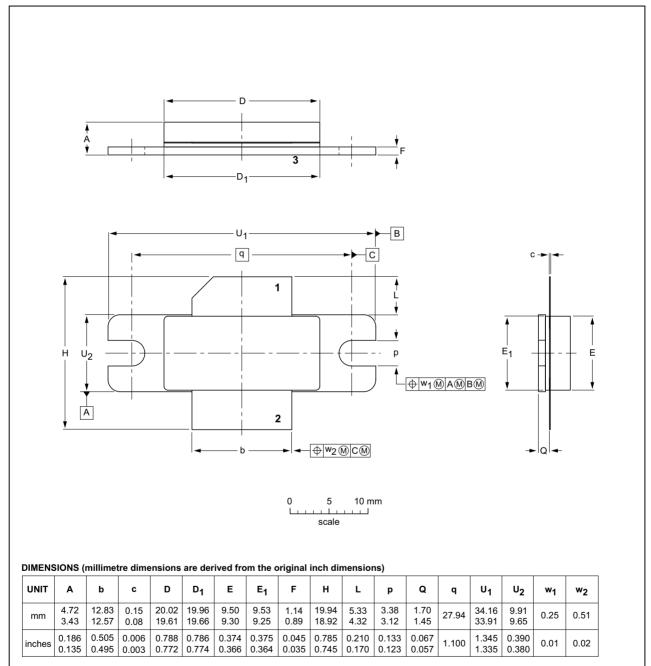
- (1) $V_{DS} = 50 \text{ V}$
- (2) $V_{DS} = 45 \text{ V}$
- (3) $V_{DS} = 40 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

8. Package outline



SOT502A



| OUTLINE | DUTLINE REFERENCES | | EUROPEAN | IOOUE DATE | |
|---------|--------------------|-------|----------|------------|------------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT502A | | | | | -03-01-10 - 12-05-02 |

Fig 11. Package outline SOT502A

Earless flanged ceramic package; 2 leads

SOT502B

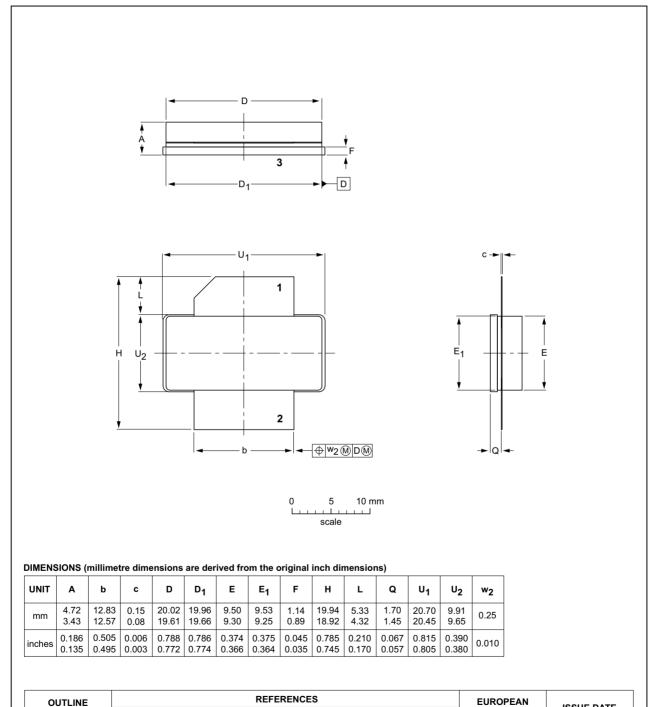


Fig 12. Package outline SOT502B

IEC

JEDEC

VERSION

SOT502B

JEITA

ISSUE DATE

07-05-09

12-05-02

PROJECTION

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

| ESD model | Class |
|--|-------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C1 🗓 |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

- [1] CDM classification C1 is granted to any part that passes after exposure to an ESD pulse of 250 V, but fails after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 11. Abbreviations

| Acronym | Description | |
|---------|--|--|
| CW | Continuous wave | |
| ESD | ElectroStatic Discharge | |
| ISM | Industrial, Scientific and Medical | |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor | |
| MTF | Median Time to Failure | |
| SMD | Surface Mounted Device | |
| VSWR | Voltage Standing-Wave Ratio | |

11. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------------------|---|--------------------|---------------|---------------------------|
| BLF0910H6L500_H6LS500 v.2 | 20170413 | Product data sheet | - | BLF0910H6L500_H6LS500 v.1 |
| Modifications: | <u>Table 8 on page 3</u> : corrected GHz to MHz | | | |
| BLF0910H6L500_H6LS500 v.1 | 20161202 | Product data sheet | - | - |

12. Legal information

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|--------------------------------|-------------------|---|
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Power LDMOS transistor

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